

Features

- Trench LV MOSFET Technology
- High Dense Cell Design for Extremely Low $R_{DS(ON)}$
- Moisture Sensitivity Level 1
- Halogen Free. "Green" Device (Note 1)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

Maximum Ratings

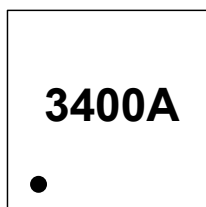
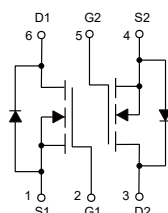
- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Maximum Thermal Resistance: 89°C/W Junction to Ambient (Note 2)

Parameter		Symbol	Rating	Unit
Drain-Source Voltage		V _{DS}	30	V
Gate-Source Volltage		V _{GS}	±12	V
Continuous Drain Current	T _A =25°C	I _D	5	A
	T _A =70°C		4	
Pulsed Drain Current ^(Note 3)		I _{DM}	20	A
Total Power Dissipation ^(Note 4)		P _D	1.4	W

Note:

1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
2. The value of R_{thJA} is measured with the device mounted on 1 in2 FR-4 board with 2oz. copper, in a still air environment with $T_A=25^\circ\text{C}$
3. Repetitive rating; pulse width limited by max. junction temperature.
4. P_D is based on max. junction temperature, using junction-ambient thermal resistance.

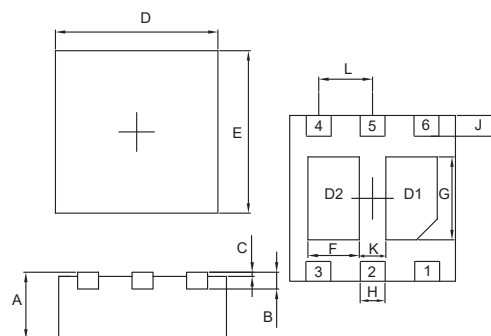
Internal Structure and Marking Code



Pin1

N-Channel MOSFET

DFN2020-6L



DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	0.030	0.034	0.750	0.850	
B	0.008		0.200		TYP.
C	0.000	0.002	0.000	0.050	
D	0.077	0.081	1.950	2.050	
E	0.077	0.081	1.950	2.050	
F	0.017	0.027	0.440	0.690	
G	0.033	0.043	0.840	1.090	
H	0.010	0.014	0.250	0.350	
J	0.007	0.015	0.175	0.375	
K	0.010	0.014	0.250	0.350	
L	0.026		0.650		TYP.

Electrical Characteristics @ 25°C (Unless Otherwise Specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =250μA	30			V
Gate-Source Leakage Current	I _{GSS}	V _{DS} =0V, V _{GS} =±12V			±100	nA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =24V, V _{GS} =0V			1	μA
Gate-Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250μA	0.7	0.9	1.5	V
Drain-Source On-Resistance	R _{DS(on)}	V _{GS} =10V, I _D =5.8A		24	32	mΩ
		V _{GS} =4.5V, I _D =5A		27	38	
		V _{GS} =2.5V, I _D =4A		32	45	
Gate Resistance	R _G	f=1MHz, Open drain		1.7		Ω
Diode Characteristics						
Continuous Body Diode Current	I _S				5	A
Diode Forward Voltage	V _{SD}	V _{GS} =0V, I _S =1A			1	V
Reverse Recovery Time	t _{rr}	I _F =5A, dI _F /dt=280A/μs		10		ns
Reverse Recovery Charge	Q _{rr}			11		nC
Dynamic Characteristics						
Input Capacitance	C _{iss}	V _{DS} =15V, V _{GS} =0V, f=1MHz		645		pF
Output Capacitance	C _{oss}			58		
Reverse Transfer Capacitance	C _{rss}			50		
Total Gate Charge	Q _g	V _{DS} =15V, V _{GS} =10V, I _D =5A		16		nC
Gate-Source Charge	Q _{gs}			1.5		
Gate-Drain Charge	Q _{gd}			2.3		
Turn-On Delay Time	t _{d(on)}	V _{DD} =20V, V _{GS} =10V, R _G =2.2Ω, I _D =5A		7		ns
Turn-On Rise Time	t _r			28		
Turn-Off Delay Time	t _{d(off)}			18		
Turn-Off Fall Time	t _f			2		

Curve Characteristics

Fig. 1 Typical Output Characteristics

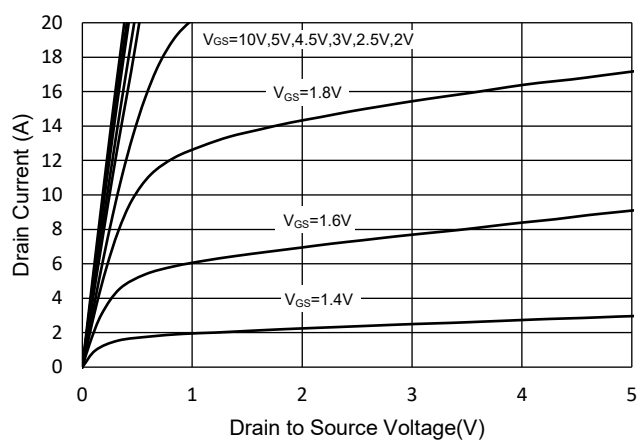


Fig.2 Transfer Characteristic

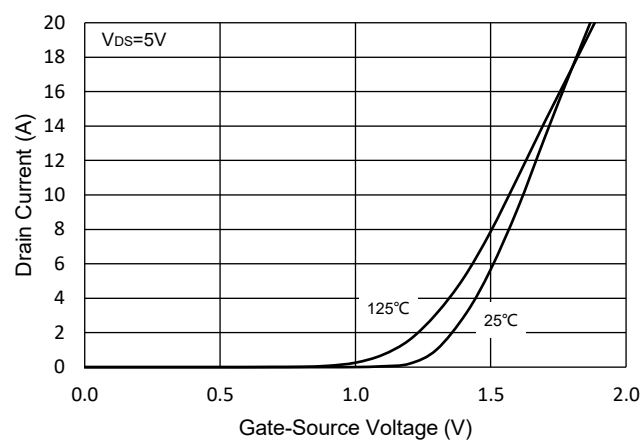


Fig.3 Rdson-Vgs

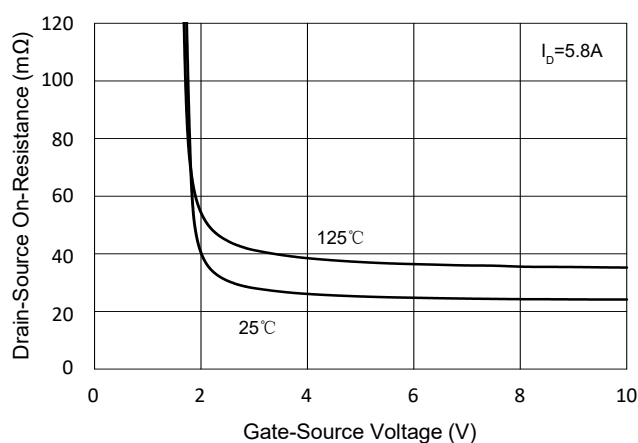


Fig.4 Rds(ON)-ID

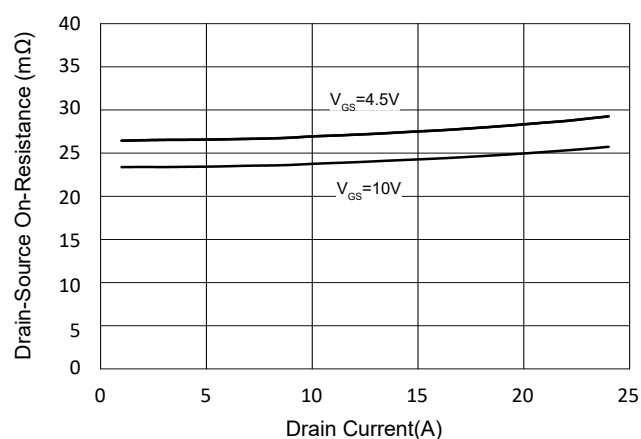


Fig.5 Capacitance Characteristics

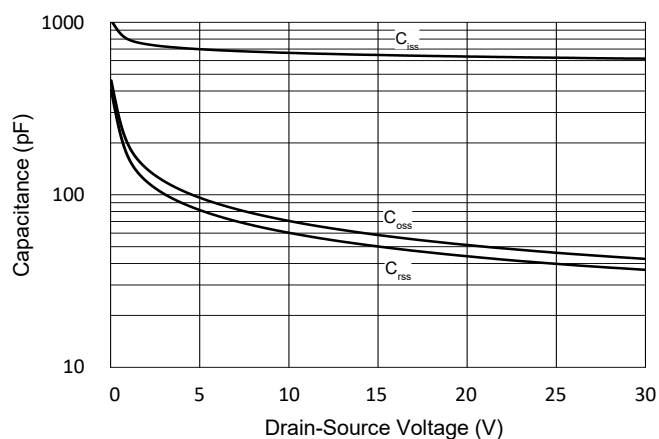
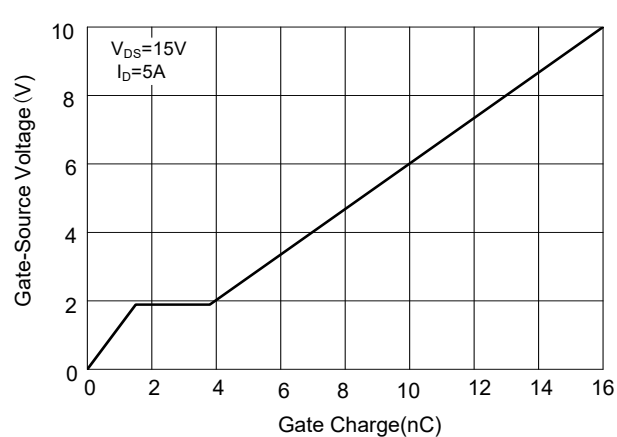


Fig.6 Gate Charge



Curve Characteristics

Fig.7 Normalized Threshold Voltage

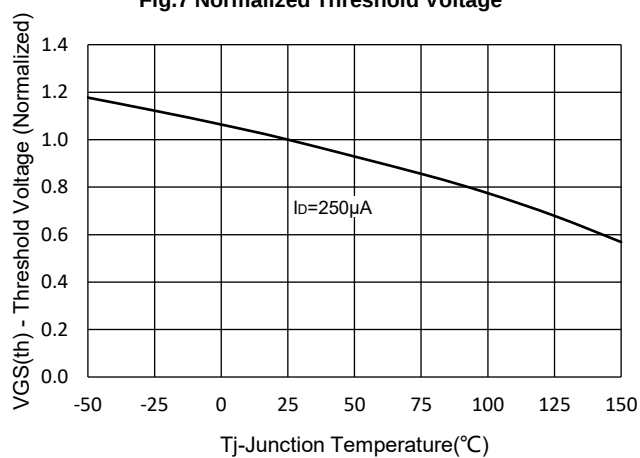


Fig.8 Normalized On Resistance Characteristics

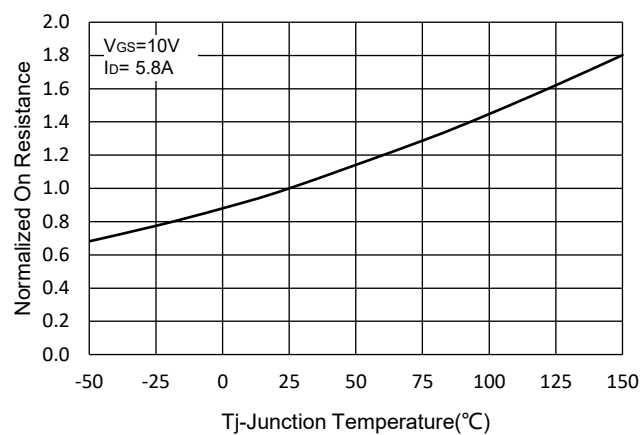


Fig.9 IS-VSD

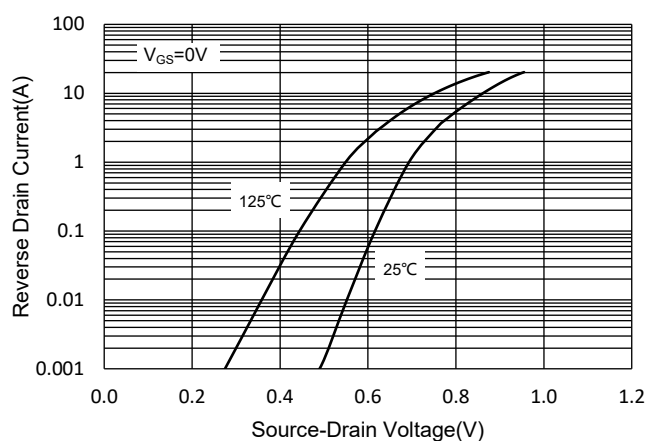


Fig.10 Drain Current

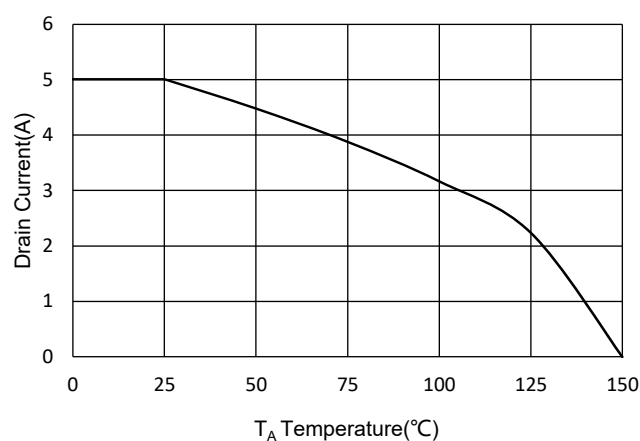
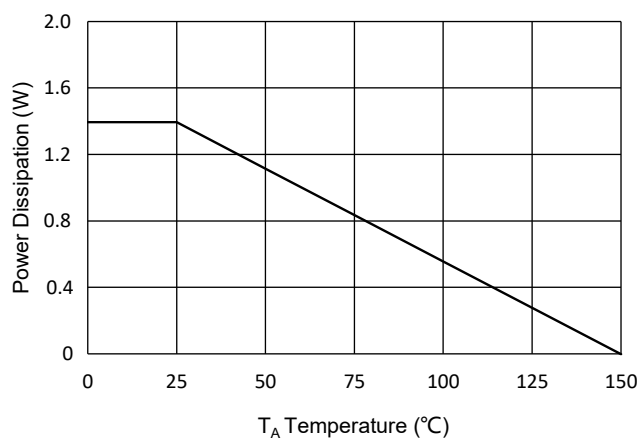


Fig.11 Power Dissipation



Curve Characteristics

Fig.12 Safe Operation Area

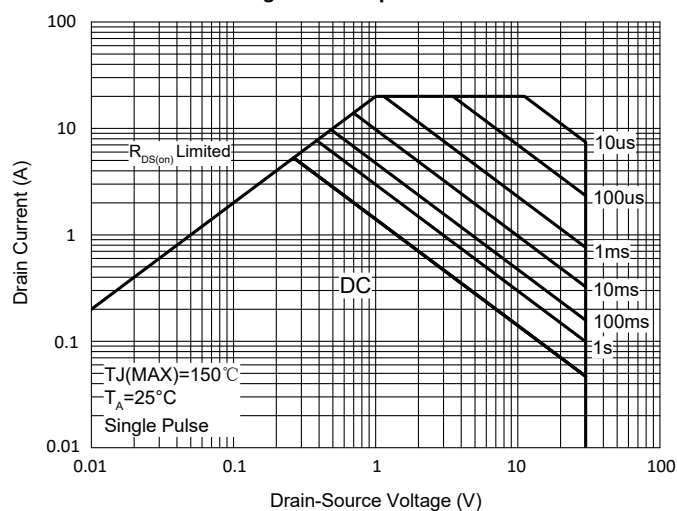
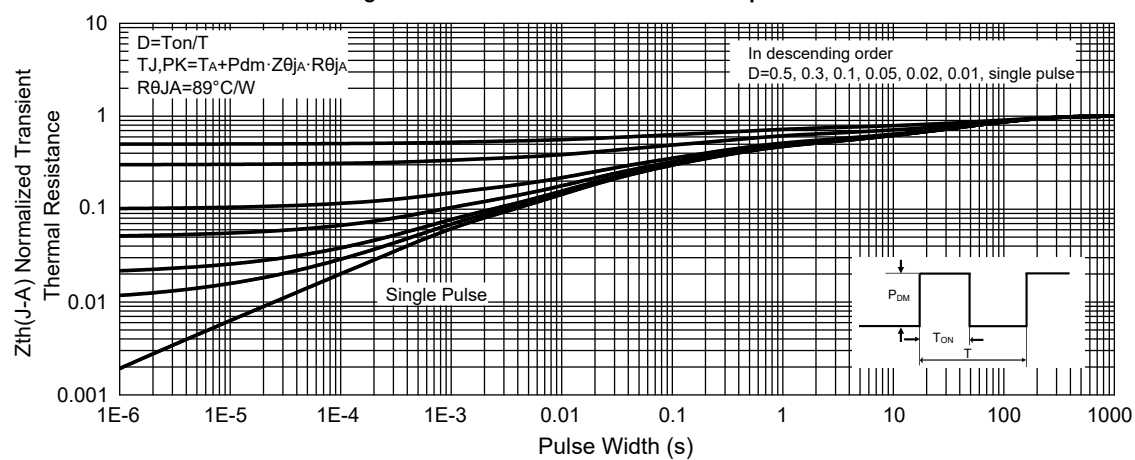


Fig.13 Normalized Transient Thermal Impedance



Ordering Information

Device	Packing
Part Number-TP	Tape&Reel:3Kpcs/Reel

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